آ'ني	L Number	Hits	Search Text	DB	Time stamp
	1	1	"20030001222"	USPAT;	2003/03/20 09:19
				US-PGPUB;	
				EPO; JPO;	
				DERWENT;	
	14	316	air near2 (gap\$1 hole\$1 insulat\$4	IBM_TDB USPAT;	2003/03/20 10:20
	14	310	dielectric space\$1) with (over overlap\$4)	US-PGPUB;	2003/03/20 10:20
			with (gate electrode)	EPO; JPO;	
				DERWENT;	
				IBM TDB	
	21	734		USPAT;	2003/03/20 10:46
			dielectric space\$1) with (gate)	US-PGPUB;	
				EPO; JPO;	
			•	DERWENT;	
ŀ	28	682	 (air near2 (gap\$1 hole\$1 insulat\$4	IBM_TDB USPAT;	2003/03/20 10:22
	20	002	dielectric space\$1) with (gate)) not (air	US-PGPUB;	2003/03/20 10.22
			near2 (gap\$1 hole\$1 insulat\$4 dielectric	EPO; JPO;	
			space\$1) with (over overlap\$4) with (gate	DERWENT;	
			electrode))	IBM TDB	
	35	133	((air near2 (gap\$1 hole\$1 insulat\$4	USPĀT;	2003/03/20 12:22
			dielectric space\$1) with (gate)) not (air	US-PGPUB;	·
			near2 (gap\$1 hole\$1 insulat\$4 dielectric	EPO; JPO;	
			space\$1) with (over overlap\$4) with (gate electrode))) and (438/\$6 257/\$6)	DERWENT;	
	42	81		IBM_TDB USPAT;	2003/03/20 10:53
		0.1	dielectric space\$1) with (transistor) and	US-PGPUB;	2003/03/20 10:33
			(438/\$6 257/\$6)	EPO; JPO;	
-				DERWENT;	
				IBM TDB	
	49	68	,	USPAT;	2003/03/20 10:59
			(overlap\$4 cross crossover intersection)	US-PGPUB;	
- [and (438/\$6 257/\$6)	EPO; JPO;	
-				DERWENT; IBM TDB	
	60	n	buried near insulator with ("3" "5") with	USPAT;	2003/03/20 12:20
	1	0	(micron ".mu." mu micrometer)	US-PGPUB;	2003/03/20 12.20
- 1	İ	i	ļ	EPO; JPO;	
1	†	1		DERWENT;	
				IBM_TDB	
	67	132	insulator with ("3" "5") with (micron	USPAT;	2003/03/20 13:26
İ			".mu." mu micrometer)	US-PGPUB;	
	†			EPO; JPO; DERWENT;	
				IBM_TDB	
İ	74	0	((257/443,448).CCLS.) and (insulator with	USPAT;	2003/03/20 12:21
	-	-	("3" "5") with (micron ".mu." mu	US-PGPUB;	
	Ì		micrometer))	EPO; JPO;	
				DERWENT;	
	0.1		All and the Alley House House the state of t	IBM_TDB	0000 (00 (00 :
	81	42	(insulator with ("3" "5") with (micron	USPAT;	2003/03/20 12:25
	ŀ		".mu." mu micrometer)) and (438/\$6 257/\$6)	US-PGPUB; EPO; JPO;	
	1			DERWENT;	
	1			IBM TDB	
	88	0	((insulator with ("3" "5") with (micron	USPAT;	2003/03/20 12:24
	ļ		".mu." mu micrometer)) and (438/\$6	US-PGPUB;	
		1	257/\$6)) and bisbenzocyclobutene	EPO; JPO;	
	-	i		DERWENT;	
	95	0	bisbenzocyclobutene with ("3" "5") with	IBM_TDB	2002/02/20 10:04
	<i>-</i> -	٠ :	(micron ".mu." mu micrometer)	USPAT; US-PGPUB;	2003/03/20 12:24
	ļ	Ì	(MICION .MG. MG MICIOMETEL)	EPO; JPO;	
				DERWENT;	
		İ		IBM TDB	
	102	14	bisbenzocyclobutene and ("3" "5") with	USPĀT;	2003/03/20 13:33
			(micron ".mu." mu micrometer)	US-PGPUB;	
		-		EPO; JPO;	
		İ		DERWENT;	
1_	l_			IBM_TDB	

,*				
109	0	(bisbenzocyclobutene and ("3" "5") with	USPAT;	2003/03/20 13:32
		(micron ".mu." mu micrometer)) and (438/\$6	US-PGPUB;	
		257/\$6)	EPO; JPO;	
			DERWENT;	
1			IBM_TDB	
116	249	dielectric with ("3" "5") near2 (micron ".mu." mu micrometer)	USPAT;	2003/03/20 13:27
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
123	26	(dielectric with ("3" "5") near2 (micron ".mu." mu micrometer)) and (438/\$6 257/\$6)	USPAT;	2003/03/20 13:59
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
130	2	("5623161").PN.	USPAT;	2003/03/20 13:59
133		(0020202) 12111	US-PGPUB;	2003/03/20 13:33
			EPO; JPO;	
			DERWENT;	
1			IBM TDB	!

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